

Comparison of laser receivers for use at one micron wavelength

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Abstract- Space-based lidar instruments must be able to detect extremely weak laser return signals from orbital distance. The signals have a wide dynamic range caused by the variability in atmospheric transmission and surface reflectance under a fast moving spacecraft. Ideally, lidar detectors should be able to detect laser signal return pulses at the single photon level and produce linear output for multiple photon events. They should have high quantum efficiency in the near-infrared wavelength region where high-pulse-energy space-qualified lasers are available. Silicon avalanche photodiode (APD) detectors have been used in most space lidar receivers to date. Their sensitivity is typically hundreds of photons per pulse at 1064 nm, and is limited by the quantum efficiency, APD gain noise, dark current, and preamplifier noise. NASA is developing photon-sensitive near-infrared detectors with linear response for possible use on the next generation direct-detection space lidars. We present our measurement results and a comparison of their performance.

I. INTRODUCTION

In 2007 the National Research Council (NRC), responded to requests from the National Aeronautics and Space Administration (NASA) Office of Earth Science, the National Oceanic and Atmospheric Administration (NOAA) National Environmental Satellite Data and Information Service (NESDIS), and the U.S. Geological Survey (USGS) Geography Division to conduct a decadal survey to generate consensus recommendations from the Earth and environmental science and applications communities regarding a systems approach to space-based and ancillary observations that encompasses the research programs of NASA; the related operational programs of NOAA; and associated programs such as Landsat, a joint initiative of USGS and NASA. The NRC recommended a total of fifteen missions¹ with benefits range from information for short-term needs, such as weather forecasts and warnings for protection of life and property, to the longer-term scientific understanding necessary for future applications that will benefit society in ways still to be realized. Three out of the fifteen recommended missions are laser based

instrument for topography mapping of the Earth's surface. These are the Ice, Cloud, and Land Elevation Satellite-II (ICESat-II), Deformation, Ecosystem Structure and Dynamics of Ice (DESDynI) as tier-1 missions and Lidar Surface Topography (LIST) as a third tier mission. These three missions could all possibly benefit from a very low-noise (near single-photon sensitive), high-bandwidth (1 GHz), near-infrared optical receiver. Improvements in detector quantum efficiency translate directly to reduced laser energy requirements for active laser instruments. This minimizes spacecraft resource requirements (mass, power, volume) and greatly enhances laser and system reliability.

All of NASA's space-based laser altimetry missions to date have used versions of the near-infrared enhanced silicon avalanche photodiode (APD) detector manufactured by PerkinElmer Opto-Electronics Canada (a.k.a. EG&G and formerly RCA) for detecting laser signal returns at 1064 nm wavelength. These missions include NEAR, CLEMENTINE, MOLA, ICESAT/GLAS, CALIPSO, MLA and LOLA. The spaceflight optical receivers are based on custom-built improved versions of the commercial Model C30954E APD. Its RF bandwidth of 140 MHz is matched to the laser transmitter pulse bandwidth. The Si APDs exhibit low excess noise factor and low noise (NEP of 40~50 fW/rt(Hz) over a bandwidth of 140 MHz). This silicon APD-based optical receiver is described in detail in recent publications [2, 3]. A recent result [4] was an NEP of 5 fW/rt(Hz) with 200 MHz bandwidth.

The laser altimeter system RF signal bandwidth is designed [5] for a specific spatial resolution and average surface topography roughness. For the space-based ICESat/GLAS instrument, these parameters were 70-meter diameter ground area, surface slope varying from 0-30 degrees and 140 MHz RF signal bandwidth (corresponding to the (-20 dB) bandwidth for a 6 ns laser transmitter pulse width). NASA's future laser altimeters plan to have a higher spatial resolution. A topographic mapping spatial resolution of 5

meters is planned for the LIST mission. This increases the RF (-20 dB) signal bandwidth to greater than 1 GHz and reduces the corresponding laser pulse width to less than 1 ns. The 1 ns pulse width also provides higher height resolution and increased probability of ground location detection under trees for reasonably flat (< 3 degree surface slope) regions. Si photoreceivers do not meet these requirements. At 1.06 μm , in order to get reasonable absorption, a very thick absorber (several tens of microns) is necessary. The thick absorber limits the Si APD bandwidth to less than a few hundred MHz. On the other hand, III-V compound semiconductor based APDs, like InGaAs APDs, show high quantum efficiency in the 1 to 1.6 μm wavelength region and fast response [2]; bandwidths greater than several GHz are commonly achieved with these APDs. However, current InGaAs APDs have NEP higher than > 500 fW/ $\sqrt{\text{Hz}}$ due to the use of high excess noise InP layer as a multiplier.

There are several reasons that make it difficult to extend the near-infrared-enhanced-silicon APD RF bandwidth to 1 GHz. First, a minimum diameter is required to match the laser ground footprint diameter image size for a practical telescope optics f-number. This leads to a larger device capacitance that contributes to the limiting the maximum bandwidth. Second, increasing the device thickness to possibly further enhance the absorption length is not fruitful because it increases the noise current and it increases the electron drift time. Therefore a new detector is required for future NASA lidar missions that require 1 GHz RF bandwidth.

In 2009, we proposed and were awarded a NASA Earth Science Technology Organization (ESTO) Advanced Component Technology (ACT) program to pursue new detector development. Our idea is to use the impact ionization engineered (I²E) material system in Indium Aluminum Arsenide (InAlAs) to simultaneously achieve high near-infrared quantum efficiency (75%), large diameter (200 mm), > 1 GHz bandwidth and high sensitivity (low-noise – 300 fW/ $\sqrt{\text{Hz}}$). In 2007, we began work on an Instrument Incubator Program (IIP) to advance and demonstrate needed technologies for the LIST mission with the Airborne LIST Simulator (A-LISTS) pathfinder instrument [6]. A-LISTS is a micropulse, waveform recording system that is based on a new, and highly efficient laser measurement approach utilizing emerging laser transmitter and the I²E APD and intensified photodiode (IPD) detector technologies described here.

1. LOW EXCESS NOISE APDS

APDs convert light signals into electrical signals with a gain from an avalanche process. Both photo generated holes and electrons could initiate an avalanche process. The excess noise could be characterized by $k=\alpha/\beta$ or β/α ($k<1$ always), where α and β are electron and hole ionization coefficients. APD excess noise and response speed (gain bandwidth

product) are determined by k value. For low noise and high speed applications, a small k value is critical. Common semiconductor materials excess noise factors are summarized in Figure 1.

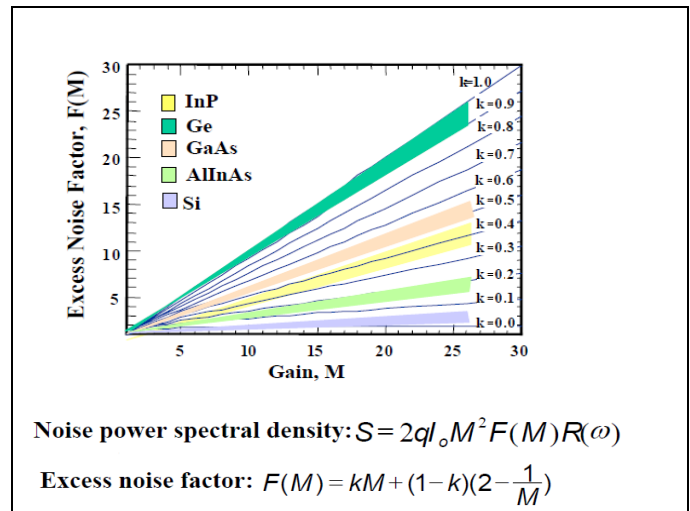
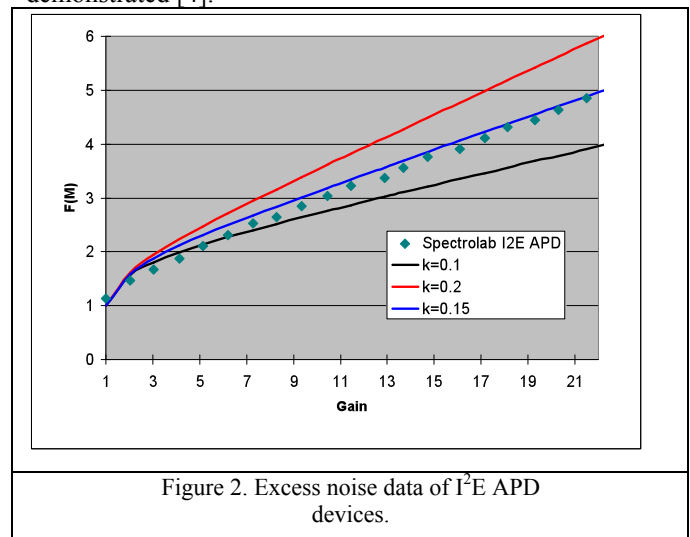


Figure 1. Excess noise factors for commonly used semiconductor materials.

There are several approaches to reduce the k value in InGaAs APDs [3]. Spectrolab has been developing InGaAs APDs with InAlAs material as a multiplication layer and InAlAs has a lower k value (0.22) [2], than commonly used InP (0.5). In order to reduce the k-value further by engineering the impact ionization values of InAlAs based heterojunction multiplication layers and these structures were called I²E structures. In this approach, the multiplier layers of the APD consist of two different semiconductors with different ionization threshold energies. It turns out that the probability of avalanche events is higher in the semiconductor with lower ionization threshold energy. This preference translates into low noise because the avalanche events become less random. k value of 0.1 has been demonstrated [4].



Excess noise values were measured on I^2E APDs and the data are shown in figure 2. The solid lines correspond to k value of 0.1, 0.15, and 0.2. The Spectrolab I^2E APD shows k value less than 0.1 at low gain regime due to the dead space effect. At high gain regime, the k value tends to fall on a value of 0.15, which is considerably lower than the InP (0.5) and the InAlAs (0.22). The measurement results are really encouraging for I^2E approach. One advantage of I^2E method is that it does not rely on the dead space effect, which could yield low k value with multiplier less than $0.1 \mu\text{m}$ thick. The thin multiplier APDs tend to suffer from high dark current from tunneling. Also, it is difficult to grow uniform thin multiplier APD arrays. The Spectrolab I^2E APDs have a much thicker multiplier, which show very low dark current and good uniformity.

One dimensional APD arrays were fabricated to characterize the wafer uniformity. The arrays had a pitch of $250 \mu\text{m}$ and each individual APD had a mesa diameter of $75 \mu\text{m}$. For 16 APDs, with a span of 4 mm, the breakdown voltage variation was less than 200 mV across the array. The variations on the photo current were the result of different incident light power on each APD during the measurement. The APDs showed low dark currents; at gain of 10, the average dark current of the APD array was 1.34 nA with a standard deviation of 0.034 nA. Devices also showed high optical gain; an optical gain over 50 was achieved.

At $1.06 \mu\text{m}$, the APD quantum efficiency is 70% and the quantum efficiency can be further improved by depositing gold metal layer on the backside of APDs and we estimate quantum efficiency will increase to about 85% at $1.06 \mu\text{m}$. Photoreceivers were built by integrating I^2E APD devices with a low noise GHz transimpedance amplifier (TIA) and photoreceivers showed a bandwidth of 1GHz and an noise equivalent power (NEP) of less than 150 fW/rt(Hz) at room temperature. We believe the performance could be significantly improved by using a custom transimpedance amplifier rather than the present commercial low-cost TIA.

2. INTENSIFIED PHOTODIODES

The intensified photodiode (IPD) detector, (a.k.a hybrid photomultiplier tube (HPMT) or hybrid photodetector (HPD)), provides high-gain with low-noise suitable for single-photon sensitivity via electron bombardment of an avalanche diode. Advantages of the IPD include large detector area (1 mm for a single channel device), high maximum count rates ($> 200 \text{ Mcps}$), high bandwidth (GHz), low afterpulsing, and near room temperature operation. Further features include low dark noise, large dynamic range for full analog pulse received waveform preservation and photon number resolution. Operating principles and performance results of previous IPDs have been reported for use at visible [7], and near-infrared [8, 9, 10], wavelengths. In recent work, we produced a 16-channel IPD with an InGaAsP photocathode for use at 1064 nm wavelength. Each channel has a $159 \mu\text{m} \times 159 \mu\text{m}$ sensitive detection area at the photocathode. Figure 3 shows the timing jitter

(188 ps FWHM, 78 ps one-sigma) measurement results for our $0.8 \mu\text{m}$ thick InGaAsP photocathode. We measured the timing jitter using two independent instruments 1) the Picoquant HydraHarp 400 multichannel scaler providing 188 ps FWHM measurement and an Agilent Model DSA91304A (13GHz BW) oscilloscope that calculated the one sigma jitter directly from the waveform histogram as 78 ps. This is an upper limit on the timing jitter because it includes the photon timing uncertainty associated with the 100 ps pulse width of the experimental test laser. For further context, a visible single-channel HPD with a 1 mm diameter photocathode has 28 ps timing jitter with 46% QE at 500 nm wavelength [3].

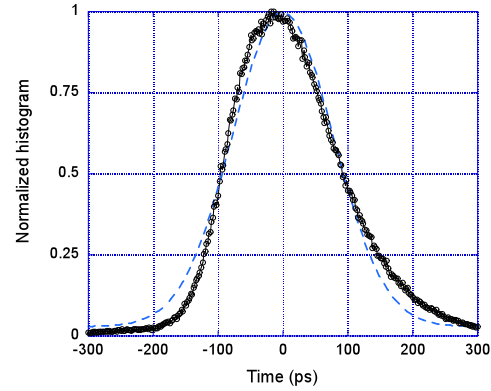


Fig. 3. Single-photon timing jitter measurement results for IPD with $0.8 \mu\text{m}$ InGaAsP layer thickness. FWHM = 188 ps. Dashed line is Gaussian fit with $\sigma = 78 \text{ ps}$.

3. Additional 16-channel IPD measured characteristics

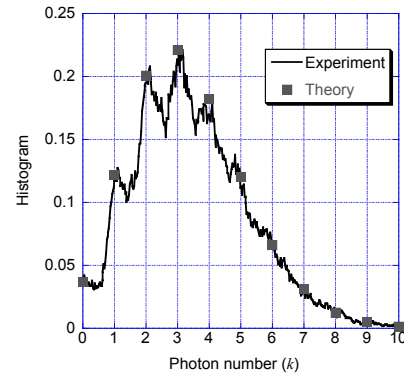


Fig. 4. Measured scaled histogram of the pulse height distribution and Poisson theory for $\lambda=3.3$

The single photon impulse response has a pulse width of 550 ps. The adjacent pixel cross talk was less than 1.1% for any pair of adjacent pixels. The internal gain is $>10^4$ for each pixel. We measured reduction of dark counts per channel with decreasing temperature and predict less than 10 kcps at -20 C .

An excess noise factor of 1.2 was measured from the pulse height amplitude distribution. Figure 4 shows excellent

agreement for two independent sets of measured photon number resolution (scaled pulse height distribution histogram) and the Poisson probability mass function

$$f(k, \lambda) = \frac{\lambda^k e^{-\lambda}}{k!} \text{ theory with } \lambda=3.3.$$

3. LASER RECEIVER SYSTEM COMPARISON

We plan to test both the 16 channel APD and IPD photoreceivers on the ALISTS instrument airborne flights. In preparation we have modeled the performance for the ALIST Swath Mapper instrument using a 10 kHz repetition rate 1030 nm Yb:YAG laser with 1 ns pulsewidth at 10 km altitude with a 5 m ground spot diameter, 3 degree surface slope, 7" diameter receiver telescope and 80 degree Sun angle.

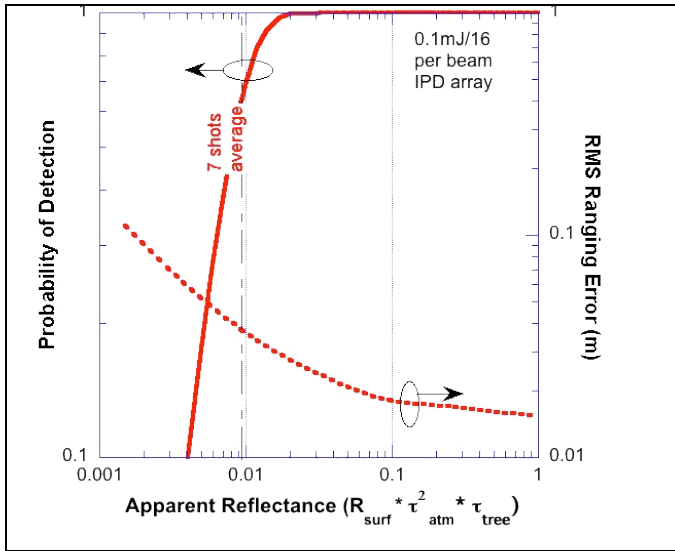


Fig. 5. ALIST Swath Mapper Performance with IPD receiver.

Figures 5 and 6 show the numerical model result of the probability of detection (left ordinate – solid curves) and the RMS ranging error (right ordinate – dashed curves) vs. the apparent surface reflectivity for the IPD (with a 0.1 mJ laser energy and 7 shot average) and I²E APD (with 1.6 mJ laser energy and 250 shot average) respectively. The system operating points of interest for comparison are circled with arrows indicating the appropriate axis. The IPD shows far superior laser receiver performance. However, the I²E APD receiver at present has far superior component reliability. Both laser receivers can achieve the same desired performance with the associated laser energies and averaging.

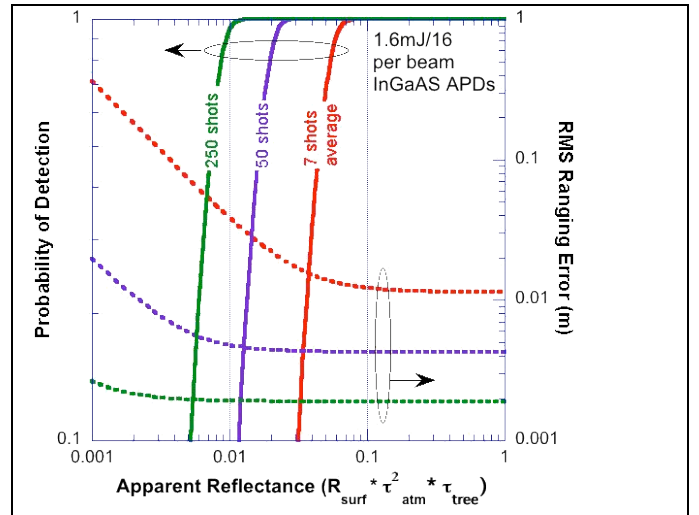


Fig. 6. ALIST Swath Mapper Performance with I2E APD receiver.

ACKNOWLEDGMENT

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